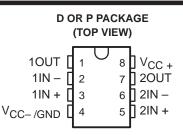
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- Wide Range of Supply Voltages Single Supply . . . 5 V to 30 V Dual Supplies . . . ± 2.5 V to ± 15 V
- Class AB Output Stage
- True Differential Input Stage
- Low Input Bias Current
- Internal Frequency Compensation
- Short-Circuit Protection

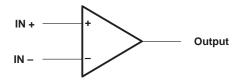
description

The TL322C and the TL322I are dual operational amplifiers similar in performance to the uA741 but with several distinct advantages. They are designed to operate from a single supply over a range of voltages from 5 V to 30 V. Operation from split supplies is also possible provided the difference between the two supplies is 5 V to 30 V. The common-mode input range includes the negative supply. Output range is from the negative supply to V_{CC} –1.5 V. Quiescent supply currents per amplifier are typically less than one-half those of the uA741.

The TL322C is characterized for operation from 0° C to 70°C. The TL322I is characterized for operation from -40° C to 85° C.



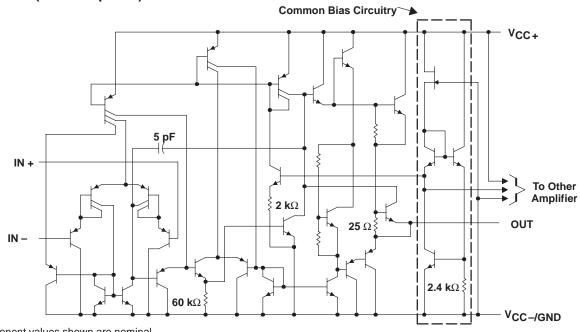
symbol (each amplifier)



	AVAIL	ABLE	OPTION	S
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		E	
TA	V _{IO} MAX AT 25°C	SMALL OUTLINE (D)	PLASTIC DIP (P)
0°C to 70°c	10 mV	TL322CD	TL322CP
0°C to 70°c	8 mV	TL322ID	TL322IP

D packages are available taped and reeled. Add R suffix to device type, (e.g., TL322CDR).



All component values shown are nominal.

schematic (each amplifier)

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

	TL322C	TL322I	UNIT
Supply voltage V _{CC+} (see Note 1)	18	18	V
Supply voltage V _{CC} (see Note 1)	-18	-18	V
Supply voltage V_{CC+} (with respect to V_{CC-})	36	36	V
Differential input voltage (see Note 2)	±36	±36	V
Input voltage (see Notes 1 and 3)	±18	±18	V
Continuous total power disspation	See Dissipation Rating Table		ole
Operating free-air temperature range	0 to 70	-40 to 85	°C
Storage temperature range	-65 to 150	-65 to 150	°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260	260	°C

NOTES: 1. These voltage values are with respect to the midpoint between V_{CC+} and V_{CC-}.

2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.

3. Neither input must ever be more positive than V_{CC+} or more negative than V_{CC-} .

DISSIPATION RATING TABLE								
PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR	DERATE ABOVE T _A	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING			
D	680 mW	5.8 mW/°C	33°C	464 mW	377 mW			
Р	680 mW	8.0 mW/°C	65°C	640 mW	520 mW			

recommended operating conditions

	MIN	NOM MAX	UNIT
Single supply voltage, V _{CC}	5	30	V
Dual supply voltage, V _{CC+}	2.5	15	V
Dual supply voltage, V _{CC} _	- 2.5	– 15	V



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electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = 15 V (unless otherwise noted)

		TEAT OCUE	TIONOT	٦	FL322C			TL322I		
	PARAMETER	TEST CONDI	TIONS	MIN	TYP	MAX	MIN	ТҮР	MAX	UNIT
V	lanut effect velteres	V _O = 0,	25°C		2	10		2	8	
VIO	Input offset voltage	R _S = 50 Ω	Full range			12			10	mV
αΛIΟ	Temperature coefficient of input offset voltage	$V_{O} = 0,$ R _S = 50 Ω	25°C		10			10		μV/°C
l	Innut offect ourrest	N = 0	25°C		30	50		30	75	-
10	Input offset current	V _O = 0	Full range			200			250	nA
αIIO	Temperature coefficient of input offset current	V _O = 0	25°C		50			50		pA/°
lun	Input biog ourrent	V _O = 0	25°C		-0.2	-0.5		-0.2	-0.5	۸
IB	Input bias current	VO = 0	Full range		-	-0.8			-1 ^µ	μA
	Common-mode input			V _{CC} -	V _{CC} -		V _{CC} -	V _{CC} -		
VICR	voltage range‡		25°C	to	to		to	to		V
	renage range			13	13.5		13	13.5		
		RL = 10 kΩ	25°C	±12	±13.5		±12	±12.5		
Vом	Peak output voltage swing	R _L = 2 kΩ	25°C	±10	±13		±10	±12		V
		KL = 2 KS2	Full range	±10			±10			
A	Large-signal differential	$V_{O} = \pm 10 V,$	25°C	20	200		20	200		
AVD	voltage amplification	$R_{L} = 2 k\Omega$	Full range	15			15			V/m
BOM	Maximum-output- swing bandwidth	$V_{O(PP)} = 20 \text{ V},$ $A_{VD} = 1,$ $THD \le 5\%,$ $R_L = 2 k\Omega$	25°C		9			9		kHz
B ₁	Unity-gain bandwidth	$V_{O} = 50 \text{ mV},$ $R_{L} = 10 \text{ k}\Omega$	25°C		1			1		MH
^φ m	Phase margin	R _L = 2 kΩ, C _L = 200 pF	25°C		60°			60°		
r _i	Input resistance	f = 20 Hz	25°C	0.3	1		0.3	1		MΩ
r _o	Output resistance	f = 20 Hz	25°C		75			75		Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR} min,$ R _S = 50 Ω	25°C	70	90		70	90		dB
ks∨s	Supply voltage sensitivity ($\Delta V_{IO} / \Delta V_{CC}$)	$V_{CC} = \pm 2.5 \text{ V to}$ $\pm 15 \text{ V},$ $R_S = 50 \Omega$	25°C		30	150		30	150	μV/\
los	Short-circuit output current§	$V_{O} = 0$	25°C	±10	±30	±45	±10	±30	±45	mA
ICC	Total supply current	V _O = 0, No load	25°C		1.4	4		1.4	4	mA

[†] All characteristics are under open-loop conditions unless otherwise noted. Full range for T_A is 0°C to 70°C for TL322C and -40°C to 85°C for TL322I.

[‡] The VICR limits are directly linked volt-for-volt to supply voltage; the positive limit is 2 V less than V_{CC+}.

§ Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.



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electrical characteristics, V_{CC+} = 5 V, V_{CC-} = 0 V, T_A = 25°C (unless otherwise noted)

PARAMETER		TEAT CONDITIONOT		TL322C			TL322I		
		TEST CONDITIONS [†]	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
VIO	Input offset voltage	$V_{O} = 2.5 \text{ V}, \text{ R}_{S} = 50 \Omega$		2	10			8	mV
lio	Input offset current	V _O = 2.5 V		30	50			75	nA
I _{IB}	Input bias current			-0.2	-0.5			-0.5	pА
		R _L = 10 kΩ	3.3	3.5		3.3	3.5		
VOM	Peak output voltage swing‡	$R_L = 10 k\Omega$, V _{CC+} = 5 V to 30 V	V _{CC+} -	V _{CC+} -1.7		V _{CC+} -1.7		V	
A _{VD}	Large-signal differential voltage amplification	$V_{O} = 1.7 \text{ V to } 3.3 \text{ V},$ R _L = 2 k Ω	20	200		20	200		V/mV
ksvs	Supply voltage sensitivity $(\Delta V_{IO} / \Delta V_{CC+})$	$V_{CC} = \pm 2.5 \text{ V to } \pm 15 \text{ V}$			150			150	μV/V
ICC	Supply current	$V_{O} = 2.5 V$, No load		1.2	4		1.2	4	mA
V ₀₁ /V ₀₂	Crosstalk attenuation	$A_{VD} = 100,$ f = 1 kHz to 20 kHz		120			120		dB

[†] All characteristics are specified under open-loop conditions.

[‡]Output will swing essentially to ground.

switching characteristics, $V_{CC+} = 15 V$, $V_{CC-} = -15 V A_{VD} = 1$, $T_A = 25^{\circ}C$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_I = \pm 10 \text{ V}, \qquad C_L = 100 \text{ pF}, \text{See Figure 1}$		0.6		V/µs
t _r	Rise time			0.35		μs
t _f	Fall time	$\Delta V_O = 50 \text{ mV}, C_L = 100 \text{ pF}, R_L = 10 \text{ k}\Omega,$ See Figure 1		0.35		μs
	Overshoot factor			20%		
	Crossover distortion	V _{I(PP)} = 30 mV, V _{O(PP)} = 2 V, f = 10 kHz		1%		

PARAMETER MEASUREMENT INFORMATION

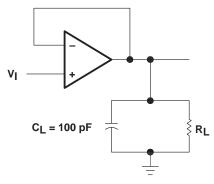
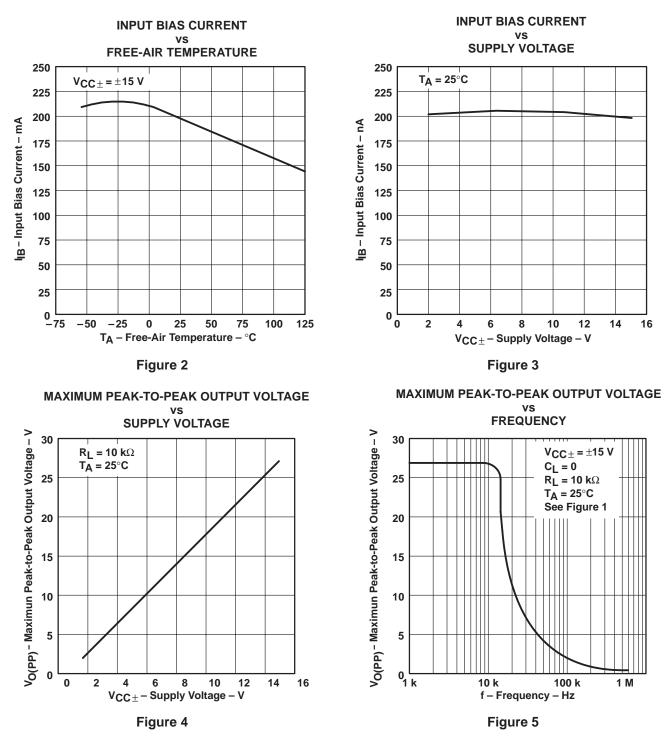


Figure 1. Unity-Gain Amplifier



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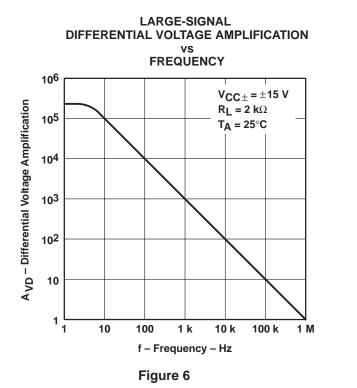


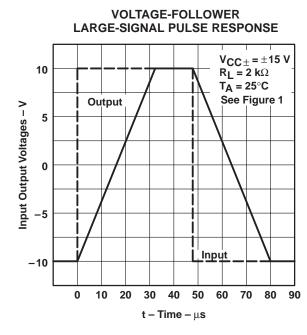


[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



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TYPICAL CHARACTERISTICS





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